Low-power dual buffer/line driver; 3-state Rev. 12 — 10 March 2022

1. General description

The 74AUP2G126 is a dual buffer/line driver with 3-state outputs controlled by the output enable inputs (nOE). Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- CMOS low power dissipation
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD78 Class II
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- Input-disable feature allows floating input conditions
- I_{OFF} circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

nexperia

3. Ordering information

Type number	Package								
	Temperature range	Name	Description	Version					
74AUP2G126DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1					
74AUP2G126GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm	SOT833-1					
74AUP2G126GF	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1 × 0.5 mm	SOT1089					
74AUP2G126GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm	SOT1116					
74AUP2G126GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm	SOT1203					
74AUP2G126GX	-40 °C to +125 °C	X2SON8	plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.35 × 0.8 × 0.35 mm	SOT1233					

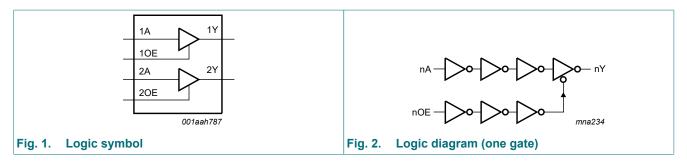
4. Marking

Table 2.	Marking	codes

Type number	Marking code[1]
74AUP2G126DC	p26
74AUP2G126GT	p26
74AUP2G126GF	pN
74AUP2G126GN	pN
74AUP2G126GS	pN
74AUP2G126GX	pN

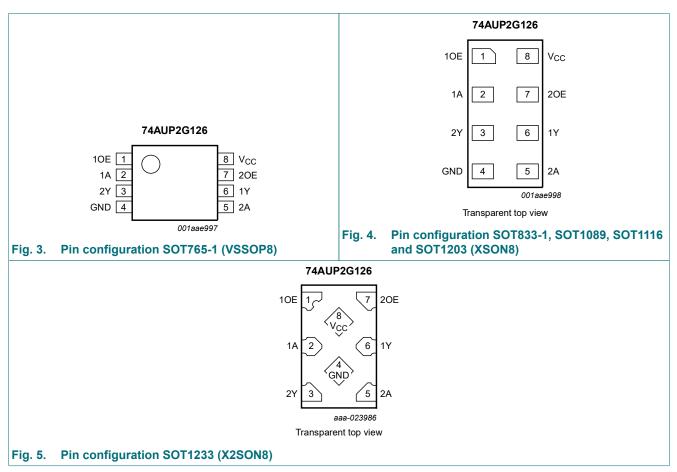
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



74AUP2G126

6. Pinning information



6.1. Pinning

6.2. Pin description

Table 3. Pin description							
Symbol	Pin	Description					
10E, 20E	1, 7	output enable input (active HIGH)					
1A, 2A	2, 5	data input					
1Y, 2Y	6, 3	data output					
GND	4	ground (0 V)					
V _{cc}	8	supply voltage					

7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

Input nOE		Output
nOE	nA	nY
Н	L	L
Н	Н	Н
L	X	Z

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{CC}	supply voltage			-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V		-50	-	mA
Vo	output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
I _O	output current	$V_{O} = 0 V$ to V_{CC}		-	±20	mA
I _{CC}	supply current			-	+50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C				
		All packages except SOT1233	[2]	-	250	mW
		SOT1233 package	[3]	-	300	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT765-1 (VSSOP8) package: P_{tot} derates linearly with 4.9 mW/K above 99 °C.

For SOT833-1 (XSON8) package: P_{tot} derates linearly with 3.1 mW/K above 68 °C.

For SOT1089 (XSON8) package: P_{tot} derates linearly with 4.0 mW/K above 88 °C.

For SOT1116 (XSON8) package: P_{tot} derates linearly with 4.2 mW/K above 90 °C.

For SOT1203 (XSON8) package: P_{tot} derates linearly with 3.6 mW/K above 81 °C.

[3] For SOT1233 (X2SON8) package: Ptot derates linearly with 7.7 mW/K above 118 °C.

9. Recommended operating conditions

Table 6. Operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	0	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = 2	5 °C					
VIH	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
, IC		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	$0.75 \times V_{CC}$	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I_0 = -2.3 mA; V_{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I_{O} = -4.0 mA; V_{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3 \times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I_0 = 2.3 mA; V_{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
I	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.1	μA
I _{OFF}	power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$	-	-	±0.2	μA
ΔI _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μA
ΔI _{CC}	additional supply current	data input; V _I = V _{CC} - 0.6 V; I _O = 0 A; [1] V _{CC} = 3.3 V	-	-	40	μA
		nOE input; V _I = V _{CC} - 0.6 V; I _O = 0 A; [1] V_{CC} = 3.3 V	-	-	110	μA
		all inputs; V_1 = GND to 3.6 V; [2] nOE = GND; V_{CC} = 0.8 V to 3.6 V	-	-	1	μA

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
CI	input capacitance	V_{I} = GND or V_{CC} ; V_{CC} = 0 V to 3.6 V	-	0.9	-	pF
Co	output capacitance	output enabled; V_O = GND; V_{CC} = 0 V	-	1.7	-	pF
		output disabled; V _O = GND or V _{CC} ; V _{CC} = 0 V to 3.6 V	-	1.5	-	pF
T _{amb} = -4	0 °C to +85 °C					1
VIH	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
Vu		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_0 = 20 \ \mu A; V_{CC} = 0.8 \ V \text{ to } 3.6 \ V$	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
lı i		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		$I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	Image: Note of the series	V
l _l	input leakage current	$V_{I} = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.5	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
ΔI _{OFF}	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V;}$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.6	μA
I _{CC}	supply current	V_1 = GND or V_{CC} ; I_0 = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.9	μA
ΔI _{CC}	additional supply current	data input; V ₁ = V _{CC} - 0.6 V; I _O = 0 A; [1] V _{CC} = 3.3 V	-	-	50	μA
		nOE input; $V_I = V_{CC} - 0.6 V$; $I_O = 0 A$; [1] $V_{CC} = 3.3 V$	-	-	120	μA
		all inputs; V _I = GND to 3.6 V; [2] nOE = GND; V _{CC} = 0.8 V to 3.6 V	-	-	1	μA

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = -	40 °C to +125 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.75 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0 0.25 × V _{CC}			V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.25 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	$0.6 \times V_{CC}$	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_0 = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
lı	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μA
l _{oz}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.75	μA
I _{OFF}	power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V; } V_{CC} = 0 \text{ V}$	-	-	±0.75	μA
ΔI _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μA
ΔI _{CC}	additional supply current	data input; V _I = V _{CC} - 0.6 V; I _O = 0 A; [1] V _{CC} = 3.3 V	-	-	75	μA
		nOE input; $V_1 = V_{CC} - 0.6 V$; $I_0 = 0 A$; [1] $V_{CC} = 3.3 V$	-	-	180	μA
		all inputs; V_1 = GND to 3.6 V; [2] nOE = GND; V_{CC} = 0.8 V to 3.6 V	-	-	1	μA

[1] [2]

One input at V_{CC} - 0.6 V, other input at V_{CC} or GND. To show I_{CC} remains very low when the input-disable feature is enabled.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 8.

Symbol	Parameter	Conditions	Т	_{amb} = 25 °	°C	T _{an} -40 °C te	_{nb} = o +85 °C	T _{an} -40 °C to	_{nb} = o +125 °C	Unit
			Min	Typ[1]	Мах	Min	Мах	Min	Мах	
C _L = 5 p	F	· · · · · · · · · · · · · · · · · · ·								
t _{pd}	propagation	nA to nY; see <u>Fig. 6</u> [2]								
	delay	V _{CC} = 0.8 V	-	20.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.8	5.5	10.5	2.5	11.7	2.5	12.9	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	3.9	6.1	2.0	7.3	2.0	8.1	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.2	4.1	1.7	6.1	1.7	6.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.6	2.6	3.6	1.4	4.3	1.4	4.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	2.4	3.1	1.2	3.9	1.2	4.4	ns
t _{en}	enable time	nOE to nY; see Fig. 7 [3]								
		V _{CC} = 0.8 V	-	71.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.8	6.2	12.4	2.6	13.6	2.6	13.6	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	4.2	6.9	2.2	7.4	2.2	7.7	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.3	5.3	1.7	5.9	1.7	6.2	ns
		V _{CC} = 2.3 V to 2.7 V	1.5	2.4	3.6	1.4	3.8	1.4	4.1	ns
		V _{CC} = 3.0 V to 3.6 V	1.3	2.0	2.9	1.2	3.2	1.2	3.4	ns
t _{dis}	disable time	nOE to nY; see Fig. 7 [4]								
		V _{CC} = 0.8 V	-	10.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	4.2	6.2	2.9	6.4	2.9	6.5	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	3.2	4.4	2.2	4.6	2.2	4.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	3.1	4.4	1.7	4.6	1.7	4.8	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	2.4	3.2	1.4	3.4	1.4	3.6	ns
		V _{CC} = 3.0 V to 3.6 V	2.1	2.8	3.6	1.2	3.7	1.2	3.8	ns

Low-power dual buffer/line driver; 3-state

Symbol	Parameter	Conditions	т	_{amb} = 25 °	°C	T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 10	pF									
t _{pd}	propagation	nA to nY; see Fig. 6 [2]								
	delay	V _{CC} = 0.8 V	-	24.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	6.4	12.3	3.0	13.8	3.0	15.2	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	4.5	7.3	1.9	8.5	1.9	9.4	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.8	5.5	1.7	6.8	1.7	7.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.2	4.2	1.6	5.3	1.6	5.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	3.0	3.8	1.6	4.6	1.6	5.2	ns
t _{en}	enable time	nOE to nY; see Fig. 7 [3]								
		V _{CC} = 0.8 V	-	75.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	7.1	14.1	3.0	15.4	3.0	15.4	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.8	8.0	2.1	8.3	2.1	8.6	ns
		V _{CC} = 1.65 V to 1.95 V	1.8	3.9	5.9	1.7	6.5	1.7	6.8	ns
		V _{CC} = 2.3 V to 2.7 V	1.5	2.9	4.2	1.4	4.5	1.4	4.8	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	2.6	3.6	1.3	3.8	1.3	4.0	ns
t _{dis}	disable time	nOE to nY; see Fig. 7 [4]								
		V _{CC} = 0.8 V	-	12.2	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.5	5.3	7.6	3.3	7.9	3.3	7.9	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.1	5.6	2.1	5.7	2.1	5.9	ns
		V _{CC} = 1.65 V to 1.95 V	2.4	4.2	5.7	1.7	5.8	1.7	6.0	ns
		V _{CC} = 2.3 V to 2.7 V	1.9	3.2	4.1	1.4	4.3	1.4	4.5	ns
		V _{CC} = 3.0 V to 3.6 V	2.4	4.1	5.0	1.3	5.2	1.3	5.3	ns

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Low-power dual buffer/line driver; 3-state

Symbol	Parameter	Conditions	T _{amb} = 25 °C		T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit	
			Min	Typ[1]	Max	Min	Мах	Min	Max	
C _L = 15	pF									
t _{pd}	propagation	nA to nY; see Fig. 6 [2]								
	delay	V _{CC} = 0.8 V	-	27.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	7.2	14.1	3.3	15.8	3.3	17.5	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.1	8.1	2.5	9.8	2.5	10.9	ns
		V _{CC} = 1.65 V to 1.95 V	2.2	4.3	6.3	2.0	7.9	2.0	8.8	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	3.7	4.9	1.8	6.0	1.8	6.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.5	4.4	1.8	5.4	1.8	6.1	ns
t _{en}	enable time	nOE to nY; see Fig. 7 [3]								
		V _{CC} = 0.8 V	-	79.2	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	7.8	15.8	3.3	17.1	3.3	17.1	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.4	8.8	2.9	9.4	2.9	9.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	4.3	6.7	2.0	7.3	2.0	7.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	3.4	4.8	1.7	5.2	1.7	5.6	ns
		V _{CC} = 3.0 V to 3.6 V	1.6	3.1	4.1	1.5	4.5	1.5	4.7	ns
t _{dis}	disable time	nOE to nY; see Fig. 7 [4]								
		V _{CC} = 0.8 V	-	14.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.3	6.4	8.5	3.7	9.3	3.7	9.4	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.0	6.6	2.5	6.9	2.5	7.0	ns
		V _{CC} = 1.65 V to 1.95 V	3.1	5.4	6.6	2.0	7.4	2.0	7.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.4	4.0	5.0	1.7	5.1	1.7	5.5	ns
		V _{CC} = 3.0 V to 3.6 V	3.2	5.3	6.2	1.5	6.7	1.5	6.9	ns

Low-power dual buffer/line driver; 3-state

Symbol	Parameter	Conditions	T _{amb} = 25 °C		T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit	
			Min	Typ[1]	Max	Min	Мах	Min	Мах	
C _L = 30	pF									
t _{pd}	propagation	nA to nY; see Fig. 6 [2]								
	delay	V _{CC} = 0.8 V	-	37.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.8	9.5	18.7	4.4	21.4	4.4	24.0	ns
		V _{CC} = 1.4 V to 1.6 V	4.0	6.7	10.8	3.0	13.0	3.0	14.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.9	5.6	8.4	2.6	10.3	2.6	11.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.7	4.8	6.3	2.5	7.8	2.5	8.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.7	4.6	5.8	2.5	7.0	2.5	8.3	ns
t _{en}	enable time	nOE to nY; see Fig. 7 [3]								
		V _{CC} = 0.8 V	-	90.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.7	10.0	20.4	4.3	22.0	4.3	22.0	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	6.9	11.3	3.7	12.0	3.7	12.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.6	5.6	8.6	3.2	9.5	3.2	10.1	ns
		V _{CC} = 2.3 V to 2.7 V	2.3	4.5	6.3	2.9	6.8	2.9	7.3	ns
		V _{CC} = 3.0 V to 3.6 V	2.2	4.2	5.8	2.7	6.4	2.7	6.7	ns
t _{dis}	disable time	nOE to nY; see Fig. 7 [4]								
		V _{CC} = 0.8 V	-	51.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	6.0	9.8	13.6	4.7	14.3	4.7	14.4	ns
		V _{CC} = 1.4 V to 1.6 V	4.5	7.7	10.5	3.0	10.7	3.0	11.0	ns
		V _{CC} = 1.65 V to 1.95 V	5.2	8.8	11.4	2.6	11.5	2.6	11.6	ns
		V _{CC} = 2.3 V to 2.7 V	3.9	6.4	7.4	2.3	9.0	2.3	10.2	ns
		V _{CC} = 3.0 V to 3.6 V	5.5	9.0	10.7	2.2	10.8	2.2	12.0	ns
C _L = 5 p	F, 10 pF, 15 p	F and 30 pF				1				
C _{PD}	power dissipation	output enabled; $f_i = 1 \text{ MHz}$; [5] $V_1 = \text{GND}$ to V_{CC}								
	capacitance	V _{CC} = 0.8 V	-	2.7	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.8	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	2.9	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.6	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.2	-	-	-	-	-	pF

[1] All typical values are measured at nominal V_{CC} .

 t_{pd} is the same as t_{PLH} and t_{PHL} . [2]

[3] t_{en} is the same as t_{PZH} and t_{PZL} .

[4] t_{dis} is the same as t_{PHZ} and t_{PLZ} . [5] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

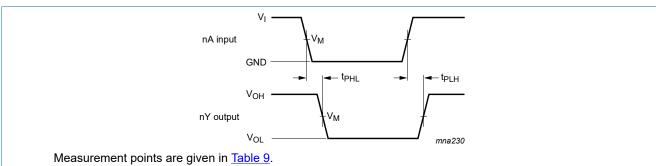
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.





Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 6. The data input (nA) to output (nY) propagation delays

Table 9. Measurement points

Supply voltage	Input	Output		
V _{cc}	V _M	VI	$t_r = t_f$	V _M
0.8 V to 3.6 V	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}

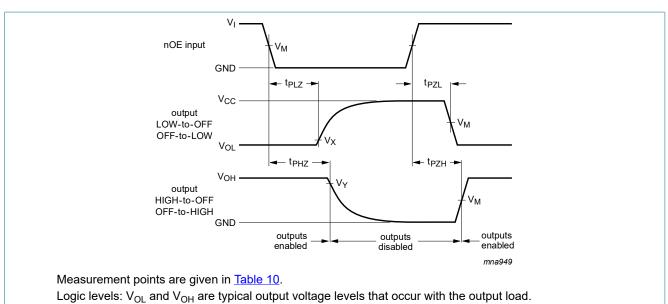


Fig. 7. Enable and disable times

Table 10. Measurement points

Supply voltage	Input	Output	Output				
V _{cc}	V _M	V _M	V _X	V _Y			
0.8 V to 1.6 V	0.5 × V _{CC}	$0.5 \times V_{CC}$	V _{OL} + 0.1 V	V _{OH} - 0.1 V			
1.65 V to 2.7 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V _{OL} + 0.15 V	V _{OH} - 0.15 V			
3.0 V to 3.6 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V _{OL} + 0.3 V	V _{OH} - 0.3 V			

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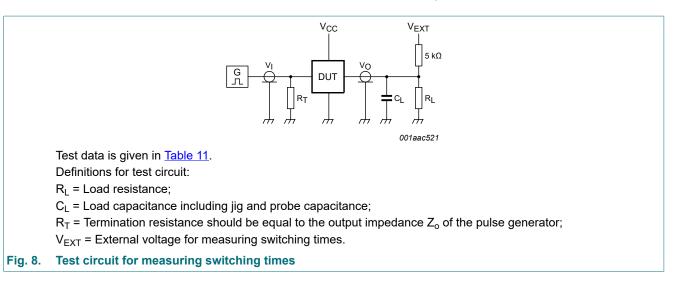


Table 11. Test data

Supply voltage	Load		V _{EXT}		
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}

[1] For measuring enable and disable times $R_L = 5 k\Omega$.

For measuring propagation delays, set-up and hold times and pulse width R_L = 1 M Ω .

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12. Package outline

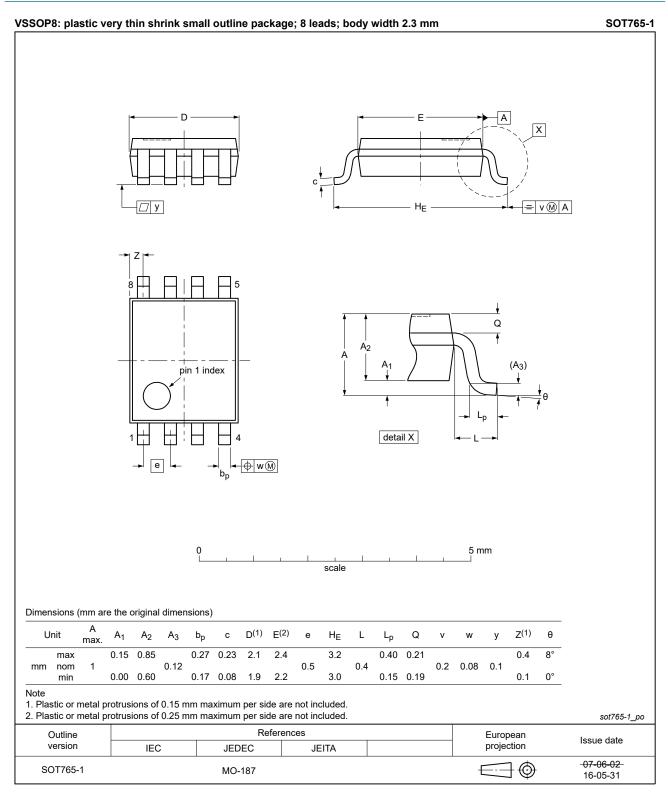


Fig. 9. Package outline SOT765-1 (VSSOP8)

Low-power dual buffer/line driver; 3-state

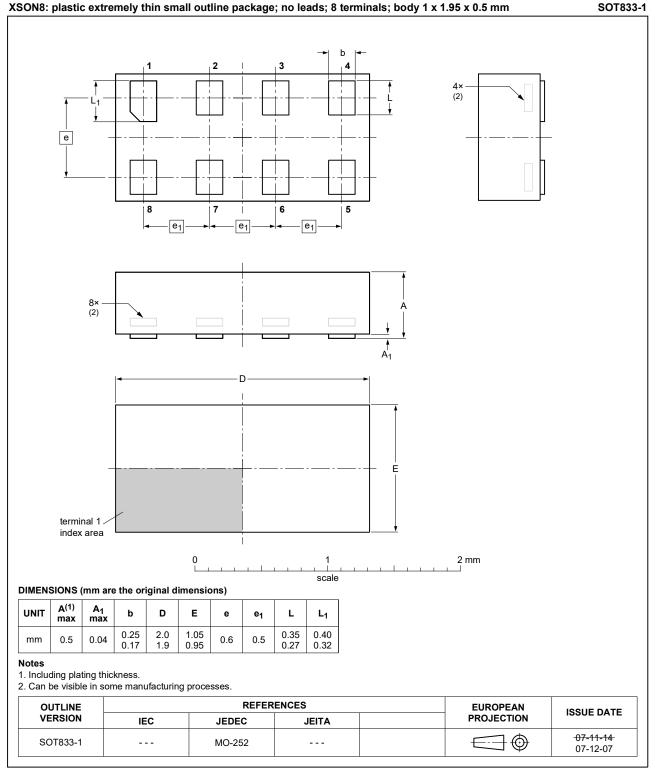
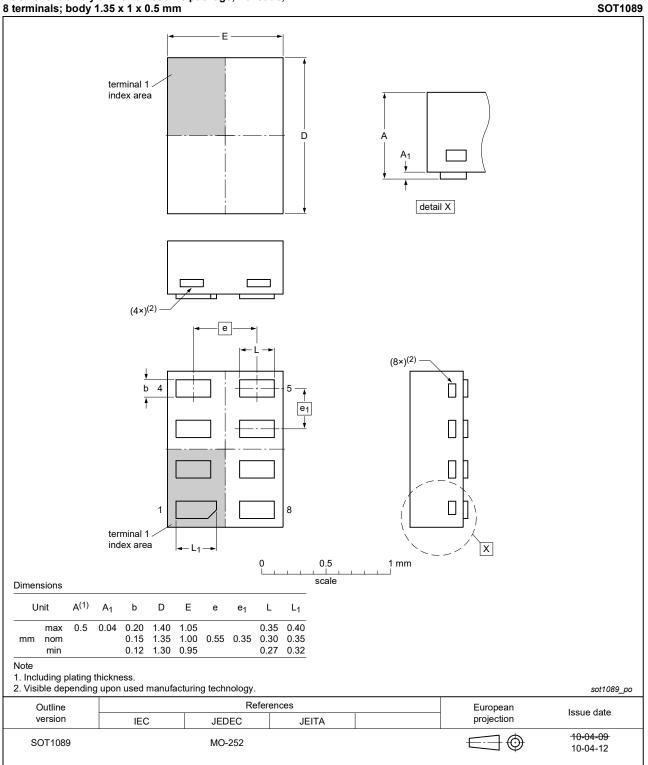


Fig. 10. Package outline SOT833-1 (XSON8)

Low-power dual buffer/line driver; 3-state

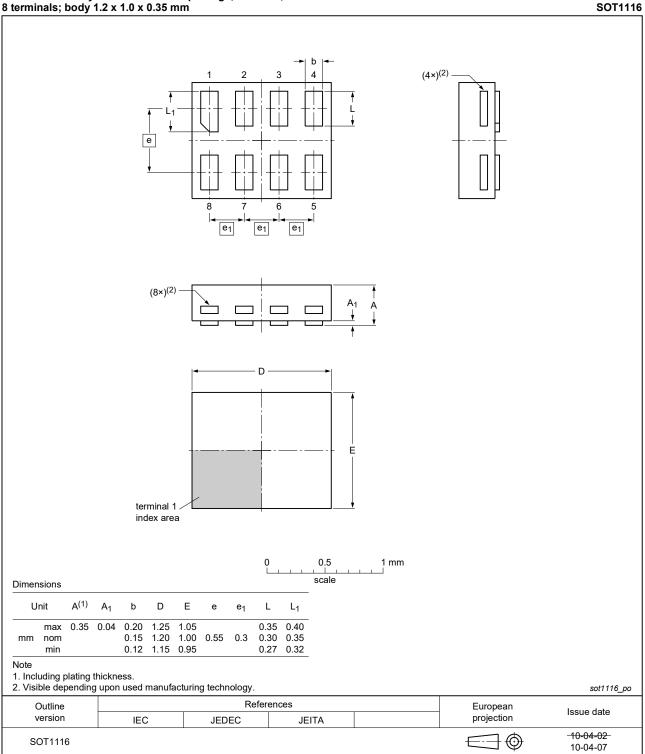


XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1 x 0.5 mm

Fig. 11. Package outline SOT1089 (XSON8)

Low-power dual buffer/line driver; 3-state

XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.2 x 1.0 x 0.35 mm





Low-power dual buffer/line driver; 3-state

XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1.0 x 0.35 mm SOT1203 b (4×)⁽²⁾ 4 2 3 е 8 6 e₁e₁ e₁ (8×)⁽²⁾ А С С ٦ D E terminal 1 index area 0.5 1 mm 0 1 1 1 scale Dimensions Unit A⁽¹⁾ A₁ b D Е L е e₁ L_1 0.35 0.04 0.20 1.40 1.05 0.35 0.40 max 0.15 1.00 0.55 0.35 0.30 0.35mm nom 1.35 min 0.12 1.30 0.95 0.27 0.32 Note 1. Including plating thickness. 2. Visible depending upon used manufacturing technology. sot1203_po References Outline European Issue date version projection IEC JEDEC JEITA 10-04-02 SOT1203 \blacksquare 10-04-06

Fig. 13. Package outline SOT1203 (XSON8)

Low-power dual buffer/line driver; 3-state

X2SON8: plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.35 x 0.8 x 0.35 mm



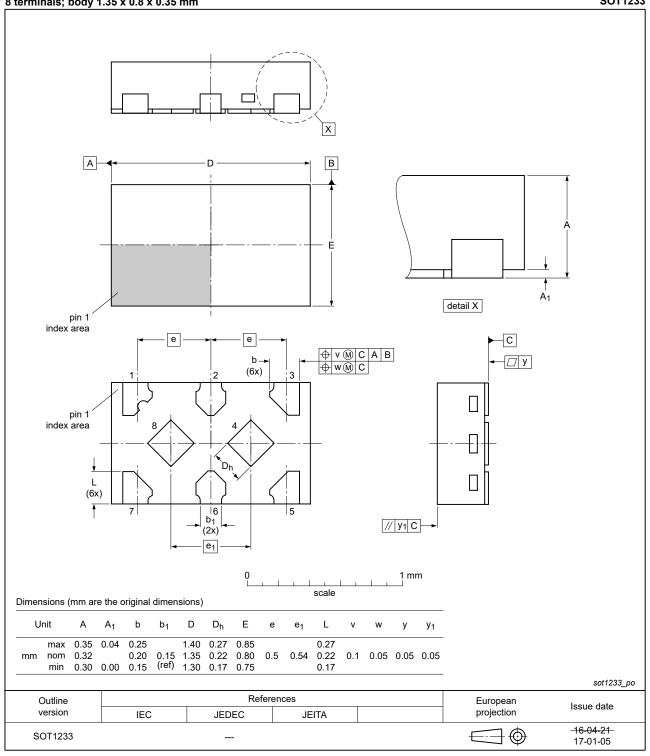


Fig. 14. Package outline SOT1233 (X2SON8)

13. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

14. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74AUP2G126 v.12	20220310	Product data sheet	-	74AUP2G126 v.11		
Modifications:	• <u>Section 1</u> a	er 74AUP2G126GM (SOT nd <u>Section 2</u> updated. rating values for P _{tot} total p				
74AUP2G126 v.11	20170703	Product data sheet	-	74AUP2G126 v.10		
Modifications:	guidelines of Legal texts Fig. 5 and F	of this data sheet has been of Nexperia. have been adapted to the Fig. 14 (drawings SOT1233 er 74AUP2G126GD remov	new company nar 3/X2SON8) update	ne where appropriate.		
74AUP2G126 v.10	20161028	Product data sheet	-	74AUP2G126 v.9		
Modifications:	Added type	Added type number 74AUP2G126GX (SOT1233/X2SON8)				
74AUP2G126 v.9	20130211	Product data sheet	-	74AUP2G126 v.8		
Modifications:	For type nu	mber 74AUP2G126GD XS	ON8U has chang	ed to XSON8.		
74AUP2G126 v.8	20120606	Product data sheet	-	74AUP2G126 v.7		
74AUP2G126 v.7	20111201	Product data sheet	-	74AUP2G126 v.6		
74AUP2G126 v.6	20100621	Product data sheet	-	74AUP2G126 v.5		
74AUP2G126 v.5	20090202	Product data sheet	-	74AUP2G126 v.4		
74AUP2G126 v.4	20090114	Product data sheet	-	74AUP2G126 v.3		
74AUP2G126 v.3	20080409	Product data sheet	-	74AUP2G126 v.2		
74AUP2G126 v.2	20070515	Product data sheet	-	74AUP2G126 v.1		
74AUP2G126 v.1	20061009	Product data sheet	-	-		

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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